Session Topic 6 -- Computation/Modeling and Simulation

Chairs: Anant Anantram, University of Waterloo Ram Mohan, North Carolina A&T Bobby Sumpter, Oak Ridge National Lab Amit Verma Irena Knezevic

TUESDAY, Room M6

Paper ID	Time	Title	Authors & Affiliations		
10:00 - 12:00 Session Chair: M. P. Anantram					
	10:00 - 10:45	Multiscale atomistic simulations of high-k MOSFETs (Invited)	Aldo DiCarlo, Univ. of Rome "Tor Vergata", Italy		
PID598476	10:45 - 11:10	High-field hole transport in small diameter silicon nanowires	Amit Verma, Texas A&M University-Kingsville, USA; Andrei Buin, University of Waterloo, Canada; M. P. Anantram, University of Waterloo, Canada; and Reza Nekovei, Texas A&M University-Kingsville, USA		
PID595689	11:10 - 11:35	Thermoelectric properties of silicon nanowires	Edwin Ramayya, University of Wisconsin - Madison, USA; Dragica Vasileska, Arizona State University, USA; Stephen Goodnick, Arizona State University, USA; and Irena Knezevic, University of Wisconsin - Madison, USA		
PID594907	11:35 - 12:00	On the Impact Ionization of Double-Gate MOSFET Using Full Band Monte Carlo Method	Ping Bai, Institute of High Performance Computing, Singapore; Ken Kai-fu Chang, Institute of High Performance Computing, Singapore; Kajen R.S, Institute of High Performance Computing, Singapore; Ganesh Samudra, National University of Singapore, Singapore; and Erping Li, Institute of High Performance Computing, Singapore		
	12:00 - 2:00	Lunch			
2:00 - 5:00	Session Ch	nair: Bobby Sumpter			
PID621398	2:00 - 2:45	On the design of low dimensional devices using atomistic computational approaches (Invited)	Vincent Meunier, Oak Ridge National Laboratory, USA		
	2:45 - 3:00	Break			
PID595732	3:00 - 3:30	Investigation of Strain Effects on the Band-structure of Si Nanowires using TB and DFT Methods	Daryoush Shiri, University of Waterloo, Canada; Yifan Kong, University of Waterloo, Canada; Andrei Buin, University of Waterloo, Canada; and M. P. Anantram, University of Waterloo, Canada		
PID593522	3:30 - 4:00	Structure Dependence of Nanoconductor Current in a Tight-Binding Microcanonical Model	Ilke Ercan, University of Massachusetts, USA; and Neal G. Anderson, University of Massachusetts, USA		
PID551802	4:00 - 4:30	Control of Charge Carriers in Molecular Devices	Sergey Lyshevski, RIT, USA; and Akhouri Sinha, Purdue University, USA		
PID590084	4:30 - 5:00	The guiding mechanism of nonradiative Surface Plasmon (SP) energy transfer along the metallic nanowire	Pinaki Mazumder, University of Michigan/NSF, USA; and Kyunyung Song, University of Michigan, Korea		
WEDNESD	AY, Room	<u>M6</u>			
9:00 - 12:00	0 Session C	hair: Ram Mohan			
PID660707	9:00 - 9:45	Currrent Status and Future Perspectives of Carbon Nanotube Interconnects (Invited)	Kaustav Banerjee, University of California Santa Barbara		
	9:45 - 10:00	Break			
PID548686	10:00 - 10:30	Equivalent Single Conductor Modeling of Carbon Nanotube Bundles for Transient Analysis of High-Speed Interconnects	Marcello D'Amore, Sapienza University of Rome, Italy; Mauro Ricci, Sapienza University of Rome, Italy; and Alessio Tamburrano, Sapienza University of Rome, Italy		

PID595915	10:30 - 11:00	Design and Modeling of Electrode Geometry for Intelligent Manufacturing and Assembly of CNT-Based Nano Devices	Uchechukwu Wejinya, University of Arkansas, United States of America; Ning Xi, Michigan State University, United States of America; King Wai Chiu Lai, Michigan State University, United States of America; and Jiangbo Zhang, Michigan State University, USA			
PID552584	11:00 - 11:30	Reliability of a QCA Array Multiplier	Ismo Hänninen, Tampere University of Technology, Finland; and Jarmo Takala, Tampere University of Technology, Finland			
PID591225	11:30 - 12:00	Quantum Mechanical Simulation of QCA with a Reduced Hamiltonian Model	Faizal Karim, UBC, Canada; Aryan Navabi, UBC, Canada; Konrad Walus, UBC, Canada; and Andre Ivanov, UBC, Canada			
	12:00 - 2:00	Lunch				
2:00 - 2:45	Session Ch	air: Irena Knezevic				
PID542465	2:00 - 2:45	Frequency Response of Nanoelectromechanical Cantilevers Operating in Fluid (Invited)	Michael Martin, Naval Research Laboratory, USA; and Brian Houston, Naval Research Laboratory, USA			
	2:45 - 3:00	Break				
PID598394	3:00 - 3:30	Prediction of Material Properties of Single Walled Carbon Nanotube using MD Simulations	Ajit Kelkar, North Carolina A&T State University, USA; Gautam Chandekar, North Carolina A&T State University, USA; and Ram Mohan, North Carolina A&T State University, USA			
PID553187	3:30 - 4:00	A fundamental Analysis of Nano-Crossbars with Non-Linear Switching Materials and its Impact on TiO2 as a Resistive Layer	Alexander Flocke, RWTH Aachen University, Germany; Carsten Kügeler, Research Center Juelich, Germany; Christian Nauenheim, Research Center Juelich, Germany; Tobias Noll, RWTH Aachen University, Germany; and Rainer Waser, Research Center Juelich, Germany			
PID596462	4:00 - 4:30	Building Blocks for Fluctuation Based Calculation in Single Electron Tunneling Technology	Saleh Safiruddin, Delft University of Technology; Sorin Cotofana, Delft University of Technology; Ferdinand Peper, National Institute of Information and Communication Technology; and Jia Lee, Celartem Technology Inc.			
PID598393	4:30 - 5:00	Molecular Dynamics Simulations of Flexural Deformation of Nickel Nanowires	Ram Mohan, North Carolina A&T State University, USA; and Yu Liang, North Carolina A&T State University, USA			
THURSDA	Y Chair: Am	it Verma				
PID595544	9:00 - 9:45	Efficient Algorithms for Protein-Based Associative Processors and Volumetric Memories (Invited)	Sanguthevar Rajasekaran, University of Connecticut, USA; Vipin Kumar, Univ. of Minnesota, USA; Sartaj Sahni, Univ. of Florida, USA; and Robert Birge, University of Connecticut, USA			
	9:45 - 10:00	Break				
PID595613	10:00 - 10:30	nanoHUB.org – online simulation and more serving annually over 60,000 users (Invited)	Gerhard Klimeck, Purdue University, USA; Michael McLennan, Purdue University, USA; Mark Lundstrom, Purdue University, USA; and George B. Adams, III, Purdue University, USA			
PID596816	10:30 - 11:00	Effect of contacts on quantum transport in nanostructures (Invited)	Bozidar Novakovic, University of Wisconsin - Madison, USA; and Irena Knezevic, University of Wisconsin - Madison, USA			
PID596320	11:00 - 11:30	OMEN an atomistic and full-band quantum transport simulator for post- CMOS nanodevices	Mathieu Luisier, Network for Computational Nanotechnology, USA; and Gerhard Klimeck, Network for Computational Nanotechnology, USA			
PID596087	11:30 - 12:00	Structure Effect of Cylindrical-Shaped GeSbTe Alloy on Phase Transition in Phase Change Memory	Yiming Li, National Chiao Tung University, Taiwan; Chih-Hong Hwang, National Chiao Tung University, Taiwan; Yi-Ting Kuo, National Chiao Tung University, Taiwan; and Hui-Wen Cheng, National Chiao Tung University, Taiwan			
	12:00 - 2:00	Lunch				
	2:00 - 2:45	Poster Session				
Poster Session (Thursday 2:00 - 2:45 pm)						
	2:00 - 2:45	Presentations for Poster session (3 minute oral indrodu	uction to poster)			
PID543923	Poster	Modeling Reliability for Single-Electron Tunneling Logic Gates	Yanjie Mao, University of Windsor, Canada; and Chunhong Chen, University of Windsor, Canada			

PID547137	Poster	Equivalent circuit model of MWCNT nanointerconnects	Maria Sabrina Sarto, Univ. of Rome Sapienza, Italy; and Alessio Tamburrano, Univ. of Rome Sapienza, Italy
PID575673	Poster	Modeling of Carbon Nanotube Schottky Diode Based on Coaxial Geometry	Alireza Kargar, Shiraz University, Iran
PID554417	Poster	Compact Model of a Dual Gate CNTFET: Description and Circuit Application	Johnny Goguet, IMS laboratory, France; Sébastien Frégonèse, IMS laboratory, France; Cristell Maneux, IMS laboratory, France; and Thomas Zimmer, IMS laboratory, France
PID554025	Poster	Investigation on the Impact Ionization Breakdown Onset of Double- Gate MOSFET structure with Optimized Hydrodynamic Model via Full- band Monte Carlo Method	Ken Chang, IHPC, Singapore
PID596503	Poster	Image Processing Algorithm for Analyzing Chirality in Carbon Nanotubes	Benjamin Bunes, Union College, USA; Palma Catravas, Union College, USA; and Michael Hagerman, Union College, USA
PID595841	Poster	An investigation of energy bandgap of monolayer and bilayer graphene nanoribbon based on different basis sets	Kai-Tak Lam, National University of Singapore, Singapore; and GENGCHIAU LIANG, National University of Singapore, Singapore
PID596339	Poster	Simulations for Vertically Coupled Wave-functions of Electrons on the Multiple Lens-shaped InAs/In(Ga)As Quantum Dot Layers with Dependences of GaAs Spacing Layer	Shiang-Feng Tang, Chung-Shan Institute of Science and Technology, Taiwan, R.O.C; Xin Nong Yang, Chung Cheng Institute of Technology, Taiwan, R.O.C; Xin-Yuan Tu, National Taiwan University, Taiwan, R.O.C; Tzu-Chiang Chen, Chung Cheng Institute of Technology, National Defense University, Taiwan, R.O.C; Sun-Tai Ping, Graduate Institute of Technology, National Chi-Nan University, Taiwan, R.O.C; and Cheng-Der Chiang, Chung-Shan Institute of Science and Technology, Taiwan, R.O.C
PID592321	Poster	On the global dynamic behavior of trapped ions in a thermal environment	Michele Bonnin, Politecnico di Torino, Italy; Pier Paolo Civalleri, Politecnico di Torino, Italy; and Marco Gilli, Politecnico di Torino, Italy
PID595773	Poster	Interaction in the Concurrently Running Replication and Self- assembly Processes	Stefan Wegrzyn, The Institute of Theoretical and Applied Informatics of the Polish Academy of Sciences, Poland; and Lech Znamirowski, Silesian University of Technology, Poland
PID652223	Poster	Micro/Nano X-Ray Tomography ReconstructionTuning Using SEM Images for PEMFC Gas Diffusion Layers	Hossein Ostadi, University of Birmingham, United Kingdom; Kyle Jiang, University of Birmingham, United Kingdom; and Phil Prewett, University of Birmingham, United Kingdom
PID595906	Poster	Fast Algorithm for Blind Estimation of Tip Shape for Atomic Force Microscope	Shuai Yuan, Shenyang Institute of Automation, Chinese Academy of Sciences, China; Ning Xi, Michigan State University, USA; Zaili Dong, Shenyang Institute of Automation, Chinese Academy of Sciences, China; Lei Miao, Shenyang Institute of Automation, Chinese Academy of Sciences, China; and Yuechao Wang, Shenyang Institute of Automation, Chinese Academy of Sciences, China
PID596093	Poster	Integrated 3-D Simulation Tool for Micro and Nano Fabrication	Guangyi Sun, Nankai University, P. R. China; Xin Zhao, Nankai University, P. R. China; Haixia (Alice) Zhang, Peking University, P. R. China; and Guizhang Lu, Nankai University, P. R. China